SMD Type Power Inductor

TPRHC1204F-SERIES

1. Features

1.Magnetic Shielded surface mount inductor with high current rating.

- 2.Low resistance to keep power loss minimum.
- 3.100% Lead(Pb) & Halogen-Free and RoHS compliant.

2. Dimension



Series	A(mm)	B(mm)	C(mm)	D(mm)	E(mm)	F(mm)
TPRHC1204F	12.8 max.	12.8 max.	5.0 max.	5.0 ref.	2.2 ref.	7.6 ref.

Units: mm

3. Part Numbering



D: Inductance

E: Inductance Tolerance

220=22.0uH , 3R9=3.9uH , 221=220uH M=±20% , Y=±30%

4. Specification

TAI-TECH Part Number	Inductance (uH)	Tolerance (%)	Test Frequency (Hz)	DCR (Ω) max.	IDC (A) max.
TPRHC 1204F-3R9Y	3.9	± 30%	1V/100K	0.015	6.50
TPRHC 1204F-4R7Y	4.7	± 30%	1V/100K	0.018	5.70
TPRHC 1204F-6R8Y	6.8	± 30%	1V/100K	0.023	4.90
TPRHC 1204F-8R2Y	8.2	± 30%	1V/100K	0.026	4.60
TPRHC 1204F-100M	10	± 20%	1V/100K	0.028	4.50
TPRHC 1204F-120M	12	± 20%	1V/100K	0.038	4.00
TPRHC 1204F-150M	15	± 20%	1V/100K	0.052	3.20
TPRHC 1204F-180M	18	± 20%	1V/100K	0.060	3.10
TPRHC 1204F-220M	22	± 20%	1V/100K	0.070	2.90
TPRHC 1204F-270M	27	± 20%	1V/100K	0.080	2.80



TAI-TECH Part Number	Inductance (uH)	Tolerance (%)	Test Frequency (Hz)	DCR (Ω) max.	IDC (A) max.
TPRHC 1204F-330M	33	± 20%	1V/100K	0.097	2.70
TPRHC 1204F-390M	39	± 20%	1V/100K	0.132	2.10
TPRHC 1204F-470M	47	± 20%	1V/100K	0.160	1.90
TPRHC 1204F-560M	56	± 20%	1V/100K	0.190	1.80
TPRHC 1204F-680M	68	± 20%	1V/100K	0.220	1.50
TPRHC 1204F-820M	82	± 20%	1V/100K	0.260	1.30
TPRHC 1204F-101M	100	± 20%	1V/100K	0.308	1.20
TPRHC 1204F-121M	120	± 20%	1V/100K	0.380	1.10
TPRHC 1204F-151M	150	± 20%	1V/100K	0.530	0.95
TPRHC 1204F-181M	180	± 20%	1V/100K	0.620	0.85
TPRHC 1204F-221M	220	± 20%	1V/100K	0.700	0.80
TPRHC 1204F-271M	270	± 20%	1V/100K	0.870	0.60
TPRHC 1204F-331M	330	± 20%	1V/100K	0.990	0.50

Note:

Based on inductance change $~~(\ \triangle L/L0 \ : \ \leq -35\%)$ @ ambient temp. 25 $^\circ\!\mathrm{C}$

Based on temperature rise $(\triangle T: 40^{\circ}C \text{ typ.})$

5. Material List



No.	ltem	Materials
1	Core	Ferrite Core (DR Type)
2	Core	Ferrite Core (RI Type)
3	Glue	Ероху
4	Wire	Copper Wire
5	Clip	The Tin Clip

6. Schematic Diagram



TAI-TECH

7. Reliability and Test Condition

ltem	Performance	Test Condition
Operating temperature	-40~+125°C (Including self - temperature rise)	
Storage temperature	-40~+125℃ (on board)	
Electrical Performance Tes	it	
		HP4284A,CH11025,CH3302,CH1320,CH1320S
Inductance	Refer to standard electrical characteristics list.	LCR Meter.
DCR		CH16502,Agilent33420A Micro-Ohm Meter.
Seturation Current (lest)	∧ I < 259/	Saturation DC Current (Isat) will cause L0
Saturation Current (Isat)	L≥3376	to drop △L(%)
		Heat Rated Current (Irms) will cause the coil temperature rise
Heat Rated Current (Irms)	Approximately AT40°C	$ riangle T(\C)$ without core loss.
		1.Applied the allowed DC current.
		2.Temperature measured by digital surface thermometer
Reliability Test		
Life Test		Preconditioning: Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles) Temperature : 125±2°C (Inductor) Applied current : rated current Duration : 1000±12hrs Measured at room temperature after placing for 24±2 hrs
Load Humidity		Preconditioning: Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles Humidity: 85±2sR.H, Temperature: 85°C ±2°C Duration: 1000hrs Min. with 100% rated current Measured at room temperature after placing for 24±2 hrs
Moisture Resistance	Appearance : No damage. Inductance : within±10% of initial value Q : Shall not exceed the specification value. RDC : within ±15% of initial value and shall not exceed the specification value	Preconditioning: Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles 1. Baked at50°C for 25hrs, measured at room temperature after placing for 4 hrs. 2. Raise temperature to 65±2°C 90-100%RH in 2.5hrs, and keep 3 hours, cool down to 25°C in 2.5hrs. 3. Raise temperature to 65±2°C 90-100%RH in 2.5hrs, and keep 3 hours, cool down to 25°C in 2.5hrs,keep at 25°C for 2 hrs then keep at -10°C for 3 hrs 4. Keep at 25°C 80-100%RH for 15min and vibrate at the frequency of 10 to 55 Hz to 10 Hz, measure at room temperature after placing for 1~2 hrs.
Thermal shock		Preconditioning: Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles Condition for 1 cycle Step1 : -40±2℃ 30±5min Step2 : 25±2℃ ≤0.5min Step3 : 125±2℃ 30±5min Number of cycles : 500 Measured at room temperature after placing for 24±2 hrs Oscillation Frequency: 10 ~ 2K ~ 10Hz for 20 minutes
Vibration		Equipment : Vibration checker Total Amplitude:1.52mm±10% Testing Time : 12 hours(20 minutes, 12 cycles each of 3 orientations)。

Item	Performance	Test Condition				
Shock	Appearance : No damage. Inductance : within±10% of initial value Q : Shall not exceed the specification value. RDC : within ±15% of initial value and shall not exceed the specification value	Type SMD Lead Shall be	Peak value (g's) 50 50 e mounted	Normal duration (D) (ms) 11 11 0n a FR4 subs	Wave form Half-sine Half-sine strate of the	Velocity change (Vi)ft/sec 11.3 11.3
Bending		following <0805:4 Bending <0805:0 duration	g dimensio l0x100x0.8 g depth: >= 0.8mm n of 10 sec.	ns: >=0805:40 3mm :0805:1.2mm	0x100x1.2mr	n
Solderability	More than 95% of the terminal electrode should be covered with solder。	Preheat Solder: 3 Tempera Flux for Dip time Depth: c	:: 150℃,60 Sn96.5% / ature: 245: lead free: e: 4±1sec₀ completely	sec.。 Ag3% Cu0.5% ±5℃。 Rosin. 9.5%。 cover the term	nination	
Resistance to Soldering Heat		Number Tem (°C) 260 : temp	tof heat cy perature ±5(solder b)	Time(s)	Temperature ramp/immersio and emersio 25mm/s ±6 r	e sion n rate nm/s
Terminal Strength	Appearance : No damage. Inductance : within±10% of initial value Q : Shall not exceed the specification value. RDC : within ±15% of initial value and shall not exceed the specification value	Precond times.(I Reflow F With the tested, a (>0805: tested. 1 applied graduall shock to	ditioning: PC/JEDEC Profiles a compone apply a for 1kg , <=0 This force : for 60 +1 ly as not to the comp	Run throu C J-STD-020D nt mounted on ce 805:0.5kg)to shall be seconds. Als apply a onent being te	igh IR in Classificatio a a PCB with the side of o the force ested.	reflow for 2 n the device to be a device being shall be applied
			DUT substrate press tool			

8. Recommended PC Board Pattern



L(mm)	G(mm)	H(mm)
12.6	7.0	5.4

9. Soldering



TAI-TECH

10. Packaging Information



2±0.1

1.5±0.25

4±0.1

600

Application Notice

24mm

Storage Conditions(component level)

To maintain the solderability of terminal electrodes:

24±0.3

- 1. TAI-TECH products meet IPC/JEDEC J-STD-020D standard-MSL, level 1.
- 2. Temperature and humidity conditions: Less than 40 $^\circ\!{\rm C}$ and 60% RH.
- 3. Recommended products should be used within 12 months form the time of delivery.

16±0.1

4. The packaging material should be kept where no chlorine or sulfur exists in the air.

Transportation

- 1. Products should be handled with care to avoid damage or contamination from perspiration and skin oils.
- The use of tweezers or vacuum pick up is strongly recommended for individual components.
 Bulk handling should ensure that abrasion and mechanical shock are minimized.



测試報告 號碼(No.): CE/2016/25436 日期(Date): 2016/03/07 頁數(Page): 1 of 11 **Test Report**

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD. (臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO, LTD.) (耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.) (慶邦電子元器件(泗洪)有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.) 桃園市楊梅區幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI, TAO-YUAN CITY, TAIWAN, R. O. C.) (江蘇省昆山市篷朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) (桃園市中壢區中壢工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI DIST, TAOYUAN CITY 320, TAIWAN) (江蘇省宿遷市泗洪縣經濟開發區金沙南路-高新技術產業園 / HIGH-TECH INDUSTRIAL DISTRICT, JINSHAJIANG ROAD, SIHONG COUNTY ECONOMIC, SUQIAN CITY, JIANGSU)

以下測試樣品係由申請廠商所提供及確認 (The following sample(s) was/were submitted and identified by/on behalf of the applicant as):

樣品名稱(Sample Description)	:	BASE TYPE CHOKE COIL/ INDUCTOR
樣品型號(Style/Item No.)	:	$\texttt{TPRH} \mathrel{\scriptstyle{\scriptstyle\bullet}} \texttt{TPS} \mathrel{\scriptstyle{\scriptstyle\bullet}} \texttt{TPH} \mathrel{\scriptstyle{\scriptstyle\bullet}} \texttt{TPL} \mathrel{\scriptstyle{\scriptstyle\bullet}} \texttt{TPRHC}$ SERIES
收件日期(Sample Receiving Date)	:	2016/02/26
測試期間(Testing Period)	:	2016/02/26 TO 2016/03/07

:

測試結果(Test Results)

請見下一頁 (Please refer to next pages).



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測試報告 Test Report

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD. (臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO. LTD.) (耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.) (慶邦電子元器件 (泗洪) 有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.) 桃園市楊梅區幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI, TAO-YUAN CITY, TAIWAN, R. O. C.) (江蘇省昆山市篷朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) (桃園市中壢區中壢工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI DIST, TAOYUAN CITY 320, TAIWAN) (江蘇省宿遷市泗洪縣經濟開發區金沙南路-高新技術產業園 / HIGH-TECH INDUSTRIAL DISTRICT, JINSHAJIANG ROAD, SIHONG COUNTY ECONOMIC, SUQIAN CITY, JIANGSU)

日期(Date): 2016/03/07

號碼(No.): CE/2016/25436

测试结果(Test Results)

測試部位(PART NAME)No.1 : 整體混測 (MIXED ALL PARTS)

测試項目 (Test Items)	單位 (Unit)	测試方法 (Method)	方法偵測 極限値 (MDL)	結果(Result) No.1
鎘 / Cadmium (Cd)	mg/kg	参考IEC 62321-5: 2013方法,以感應 耦合電漿原子發射光譜儀檢測. / With reference to IEC 62321-5: 2013 and performed by ICP-AES.	. 2	n. d.
貂 / Lead (Pb)	mg/kg	参考IEC 62321-5: 2013方法, 以感應 耦合電漿原子發射光譜儀檢測. / With reference to IEC 62321-5: 2013 and performed by ICP-AES.	2	n. d.
汞 / Mercury (Hg)	mg/kg	参考IEC 62321-4: 2013方法, 以感應 耦合電漿原子發射光譜儀檢測. / With reference to IEC 62321-4: 2013 and performed by ICP-AES.	2	n. d.
六價络 / Hexavalent Chromium Cr(VI)	mg/kg	参考IEC 62321: 2008方法, 以UV-VIS 檢測. / With reference to IEC 62321: 2008 and performed by UV- VIS.	2	n. d.
六溴環十二烷及所有主要被辨別出的異構物 / Hexabromocyclododecane (HBCDD) and all major diastereoisomers identified (α - HBCDD, β - HBCDD, γ - HBCDD) (CAS No.: 25637-99-4 and 3194-55-6 (134237-51-7, 134237-50-6, 134237-52-8))	mg/kg	參考IEC 62321: 2008方法,以氣相層 析/質譜儀檢測. / With reference to IEC 62321: 2008 method. Analysis was performed by GC/MS.	5	n. d.

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測試報告 Test Report 號碼(No.): CE/2016/25436

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD. (羅鑽科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO. LTD.) (羅鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.) (爆鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.) (慶邦電子元器件 (泗洪) 有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.) (感邦電子元器件 (泗洪) 有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.) (桃園市楊梅區幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI, TAO-YUAN CITY, TAIWAN, R. O. C.) (江蘇省昆山市篷朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) (桃園市中壢區中壢工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI DIST, TAOYUAN CITY 320, TAIWAN) (江蘇省宿邁市泗洪縣經濟開發區金沙南路-高新技術產業園 / HIGH-TECH INDUSTRIAL DISTRICT, JINSHAJIANG ROAD,

日期(Date): 2016/03/07

SIHONG COUNTY ECONOMIC, SUQIAN CITY, JIANGSU)

测試項目 (Test Items)	單位 (Unit)	測試方法 (Method)	方法偵測 極限値 (MDL)	結果 (Result) No.1
鄰苯二甲酸丁苯甲酯 / BBP (Butyl Benzyl phthalate) (CAS No.: 85-68-7)	mg/kg		50	n. d.
鄰苯二甲酸二丁酯 / DBP (Dibuty1 phthalate) (CAS No.: 84-74-2)	mg/kg		50	n. d.
鄰苯二甲酸二 (2-乙基己基)酯 / DEHP (Di- (2-ethylhexyl) phthalate) (CAS No.: 117-81-7)	mg/kg		50	n. d.
鄰苯二甲酸二異丁酯 / DIBP (Di- isobutyl phthalate) (CAS No.: 84-69- 5)	mg/kg	參考IEC 62321-8 (111/321/CD),以魚 相層析儀/質譜儀檢測之. / With reference to IEC 62321-8	50	n. d.
鄰苯二甲酸二異癸酯 / DIDP (Di- isodecyl phthalate) (CAS No.: 26761- 40-0; 68515-49-1)	mg/kg	(111/321/CD). Analysis was performed by GC/MS.	50	n. d.
鄰苯二甲酸二異壬酯 / DINP (Di- isononyl phthalate) (CAS No.: 28553- 12-0; 68515-48-0)	mg/kg	· · · · · · · · · · · · · · · · · · ·	50	n. d.
鄰苯二甲酸二正辛酯 / DNOP (Di-n- octyl phthalate) (CAS No.: 117-84-0)	mg/kg		50	n. d.
鹵素 / Halogen				
鹵素(氟)/ Halogen-Fluorine (F) (CAS No.: 14762-94-8)	mg/kg		50	n. d.
鹵素 (氯) / Halogen-Chlorine (Cl) (CAS No.: 22537-15-1)	mg/kg	参考BS EN 14582:2007,以離子層析儀 分析./ With reference to BS EN	50	n. d.
鹵素 (溴) / Halogen-Bromine (Br) (CAS No.: 10097-32-2)	mg/kg	14582:2007. Analysis was performed by IC.	50	n. d.
鹵素 (碘) / Halogen-Iodine (I) (CAS No.: 14362-44-8)	mg/kg		50	n. d.

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測試報告 Test Report ^{號碼(No.)}: CE/2016/25436

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD. (臺慶積密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO. LTD.) (耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.) (慶邦電子元器件 (泗洪) 有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.) (應邦電子元器件 (泗洪) 有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.) 桃園市楊梅區幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI, TAO-YUAN CITY, TAIWAN, R. O. C.) (江蘇省昆山市篷朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) (桃園市中壢區中壢工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI DIST, TAOYUAN CITY 320, TAIWAN)

日期(Date); 2016/03/07

頁數(Page): 4 of 11

(江蘇省宿遷市泗洪縣經濟開發區金沙南路-高新技術產業園 / HIGH-TECH INDUSTRIAL DISTRICT, JINSHAJIANG ROAD, SIHONG COUNTY ECONOMIC, SUQIAN CITY, JIANGSU)

测試項目 (Togt Itoma)	單位 (Unit)	測試方法 (Mathod)	方法偵測 極限值	結果(Result)
(Test Ttems)	(Unit)	(method)	(MDL)	No. 1
多溴聯苯總和 / Sum of PBBs	mg/kg			n. d.
一溴聯苯 / Monobromobiphenyl	mg/kg		5	n. d.
二溴聯苯 / Dibromobiphenyl	mg/kg		5	n. d.
三溴聯苯 / Tribromobiphenyl	mg/kg		5	n. d.
四溴聯苯 / Tetrabromobiphenyl	mg/kg		5	n, d.
五溴聯苯 / Pentabromobipheny1	mg/kg		5	n. d.
六溴聯苯 / Hexabromobiphenyl	mg/kg		5	n. d.
七溴聯苯 / Heptabromobiphenyl	mg/kg		5	n. d.
八溴聯苯 / Octabromobiphenyl	mg/kg		5	n. d.
九溴聯苯 / Nonabromobiphenyl	mg/kg	参考IEC 62321-6: 2015方法,以氣相	5	n. d.
十溴聯苯 / Decabromobiphenyl	mg/kg	層析/質譜儀檢測. / With reference	5	n. d.
多溴聯苯醚總和 / Sum of PBDEs	mg/kg	to IEC 62321-6: 2015 and performed	-	n. d.
一溴聯苯醚 / Monobromodiphenyl ether	mg/kg	by GC/MS.	5	n. d.
二溴聯苯醚 / Dibromodiphenyl ether	mg/kg		5	n. d.
三溴聯苯醚 / Tribromodiphenyl ether	mg/kg		5	n. d.
四溴聯苯醚 / Tetrabromodiphenyl ether	mg/kg		5	n. d.
五溴聯苯醚 / Pentabromodiphenyl ether	mg/kg		5	n. d.
六溴聯苯醚 / Hexabromodiphenyl ether	mg/kg		5	n. d.
七溴聯苯醚 / Heptabromodiphenyl ether	mg/kg		5	n. d.
八溴聯苯醚 / Octabromodiphenyl ether	mg/kg	· · · ·	5	n. d.
九溴聯苯醚 / Nonabromodiphenyl ether	mg/kg		5	n. d.
十溴聯苯醚 / Decabromodiphenyl ether	mg/kg		5	n. d.

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測試報告 Test Report

號碼(No.): CE/2016/25436

日期(Date): 2016/03/07

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西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD. (臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO. LTD.) (耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.) (慶邦電子元器件(泗洪)有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.) 桃園市楊梅區幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI, TAO-YUAN CITY, TAIWAN, R. O. C.) (江蘇省昆山市篷朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) (桃園市中壢區中壢工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI DIST, TAOYUAN CITY 320, TAIWAN) (江蘇省宿還市泗洪縣經濟開發區金沙南路-高新技術產業園 / HIGH-TECH INDUSTRIAL DISTRICT, JINSHAJIANG ROAD, SIHONG COUNTY ECONOMIC, SUQIAN CITY, JIANGSU)

備註(Note):

- 1. mg/kg = ppm; 0.1wt% = 1000ppm
- 2. n.d. = Not Detected (未檢出)
- 3. MDL = Method Detection Limit (方法偵測極限值)
- 4. "-" = Not Regulated (無規格值)
- 5. 樣品的測試是基於申請人要求混合測試,報告中的混合測試結果不代表其中個別單一材質的含量. (The samples was/were analyzed on behalf of the applicant as mixing sample in one testing. The above results was/were only given as the informality value.)

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測試報告 Test Report ^{號碼(No.)}: CE/2016/25436

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SIHONG COUNTY ECONOMIC, SUQIAN CITY, JIANGSU)

根據以下的流程圖之條件,樣品已完全溶解。(六價 絡测试方法除外) These samples were dissolved totally by pre-conditioning method according to below flow chart. (Cr^{e+} test method excluded)

- 测试人員:楊登偉 / Technician: Climbgreat Yang
- 测试負責人:張啟興 / Supervisor: Troy Chang



Note** (For IEC 62321)

(1) 針對非金局材料加入鹼性消化液 • 加熱至 90~95℃ 萃取, / For non-metallic material, add alkaline digestion reagent and heat to 90~95℃.

(2) 針對金屬材料加入純水,加熱至沸腾萃取. / For metallic material, add pure water and heat to boiling.

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测試報告 號碼(No.): CE/2016/25436 **Test Report**

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SIHONG COUNTY ECONOMIC, SUQIAN CITY, JIANGSU)

鹵素分析流程圖 / Analytical flow chart of halogen content

日期(Date): 2016/03/07

測試人員:陳恩臻 / Name of the person who made measurement: Rita Chen

測試負責人:張啟興 / Name of the person in charge of measurement: Troy Chang



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西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD. (臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO. LTD.) (糧鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.) (慶邦電子元器件 (泗洪) 有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.) (慶邦電子元器件 (泗洪) 有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.) 桃園市楊梅區幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI, TAO-YUAN CITY, TAIWAN, R. 0. C.) (江蘇省昆山市篷朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) (桃園市中壢區中壢工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI DIST, TAOYUAN CITY 320, TAIWAN) (江蘇省宿邊市泗洪縣經濟開發區金沙南路-高新技術產業園 / HIGH-TECH INDUSTRIAL DISTRICT, JINSHAJIANG ROAD,

SIHONG COUNTY ECONOMIC, SUQIAN CITY, JIANGSU)

可塑劑分析流程圖 / Analytical flow chart of phthalate content

日期(Date): 2016/03/07

■ 測試人員: 徐毓明 / Name of the person who made measurement: Andy Shu

■ 測試負責人:張啟興 / Name of the person in charge of measurement: Troy Chang



【测試方法/Test method: IEC 62321-8】

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六溴環十二烷分析流程圖 / HBCDD analytical flow chart

日期(Date): 2016/03/07

测試人員: 翁賜彬 / Name of the person who made measurement: Roman Wong 測試負責人:張啟興 / Name of the person in charge of measurement: Troy Chang



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多溴聯苯/多溴聯苯醚分析流程圖 / PBB/PBDE analytical FLOW CHART

日期(Date): 2016/03/07

测試人員: 翁賜彬 / Name of the person who made measurement: Roman Wong

测試負責人:張啟興 / Name of the person in charge of measurement: Troy Chang

初次測試程序 / First testing process -

選擇性篩檢程序 / Optional screen process ==



確認程序 / Confirmation process - - - →



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* 照片中如有箭頭標示,則表示為實際檢測之樣品/部位. * (The tested sample / part is marked by an arrow if it's shown on the photo.)

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